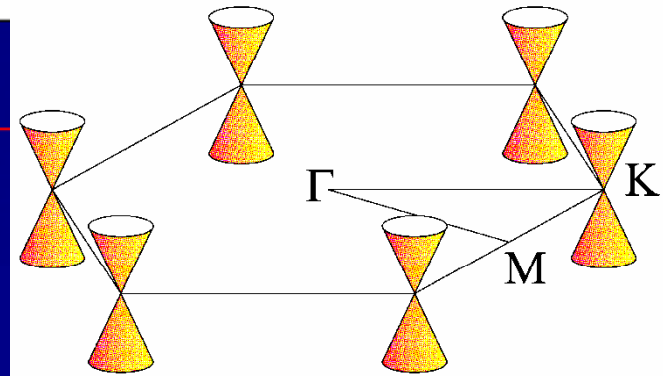
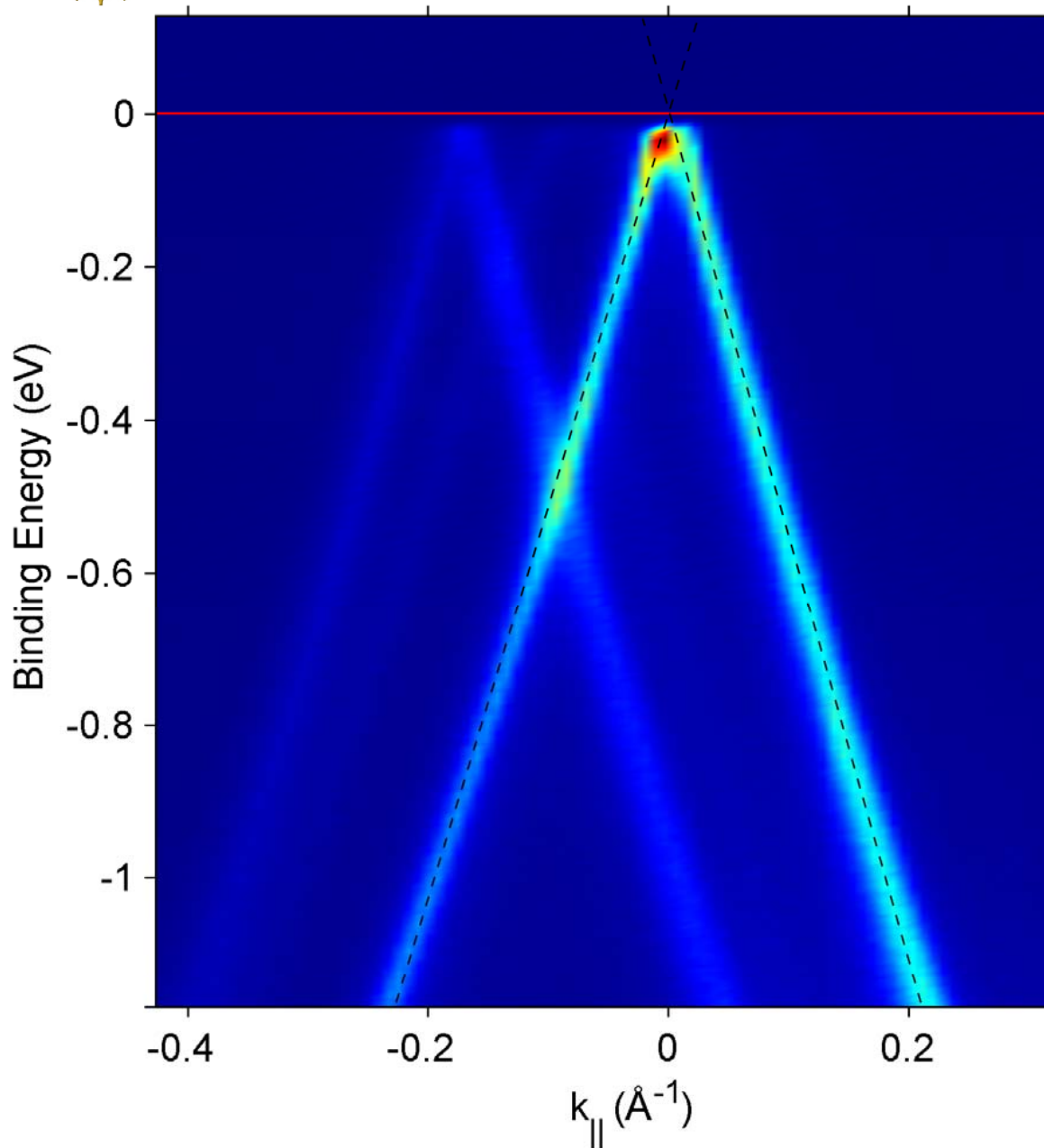




New Material Developed for Post Si-CMOS Electronics



- Multiple Dirac Cones from a 10-layer graphene film
- This Undoped Dirac Cone shows that multilayer graphene grown on the carbon face of SiC is “effectively” an electronic single graphene sheet
- This new material, discovered at the GT MRSEC for new electronic materials, makes an all graphene electronics circuit possible